## NSN 5961-00-426-4954

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View Online at https://aerobasegroup.com/nsn/5961-00-426-4954 **Inclosure Material:** Ceramic and glass and metal **Overall Length:** 0.115 inches **Overall Diameter:** 0.061 inches **Function For Which Designed:** Phototransistor **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Gold plated leads and hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 collector to emitter voltage/static/base open and 7.0 emitter-to-collector offset voltage **Power Rating Per Characteristic:** 50.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Case and terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 1 case and 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: